Diode Semiconductor Device - Page 1 of 1



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	sure Material:
Glass	
	all Length:
	inches
	inal Length:
	inches
	all Diameter:
	inches
	tion For Which Designed:
	diode
Joint	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-20	14ah
Moun	ting Method:
Termi	nal
Featu	res Provided:
Herm	etically sealed case
Semi	conductor Material:
Silico	n
Volta	ge Rating In Volts Per Characteristic:
43.0	regulator voltage
Volta	ge Tolerance In Percent:
-5.0/+	5.0
Curre	ent Rating Per Characteristic:
3.00 r	nilliamperes all primaries horsepower metric
Powe	r Rating Per Characteristic:
500.0	milliwatts small-signal input power, common-collector absolute
Maxir	num Operating Tempurature Per Measurement Point:
200.0	degrees celsius ambient air
Termi	inal Type And Quantity:
2 unin	sulated wire lead
Speci	ification Data:
80131	-release5566 professional/industrial association specification
Shelf	Life:
N/a	
Unit C	Df Measure:
Demi	litarization:
No	
Fiig:	
-	aO